## NSN 5961-01-040-1479

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View Online at https://aerobasegroup.com/nsn/5961-01-040-1479 **Inclosure Material:** Plastic **Overall Length:** Between 0.295 inches and 0.305 inches **Overall Height:** Between 0.095 inches and 0.105 inches Overall Width: 0.277 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 0.50 amperes source cutoff current and 1.50 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 27914-10248 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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